

Abstract Submitted  
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**Real-time characterization of nanostructures written at the LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface**<sup>1</sup> ALEXANDRE GAUTHIER, PATRICK IRVIN, JEREMY LEVY, University of Pittsburgh — Nanostructures can be written on the LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface using conductive AFM lithography<sup>2</sup>. These structures can be configured into devices including photodetectors<sup>3</sup> and transistors<sup>4</sup>. Characterization of complex devices requires simultaneous measurements between several pairs of electrodes. We have developed a method to take measurements between all electrodes simultaneously by both measuring and applying a bias at a unique frequency to each electrode. Fourier analysis is then used to separate measured signals by source terminal. This allows us to efficiently characterize multi-terminal devices in real-time, as they are being created. This method will allow for the use of new experimental techniques.

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<sup>2</sup>C. Cen, *et al.*, *Science* **323**, 1026 (2009)

<sup>3</sup>P. Irvin, *et al.*, *Nat. Photonics* **4**, 849 (2010)

<sup>4</sup>G. Cheng, *et al.*, *Nat. Nanotechnol.* **6**, 343 (2011)

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